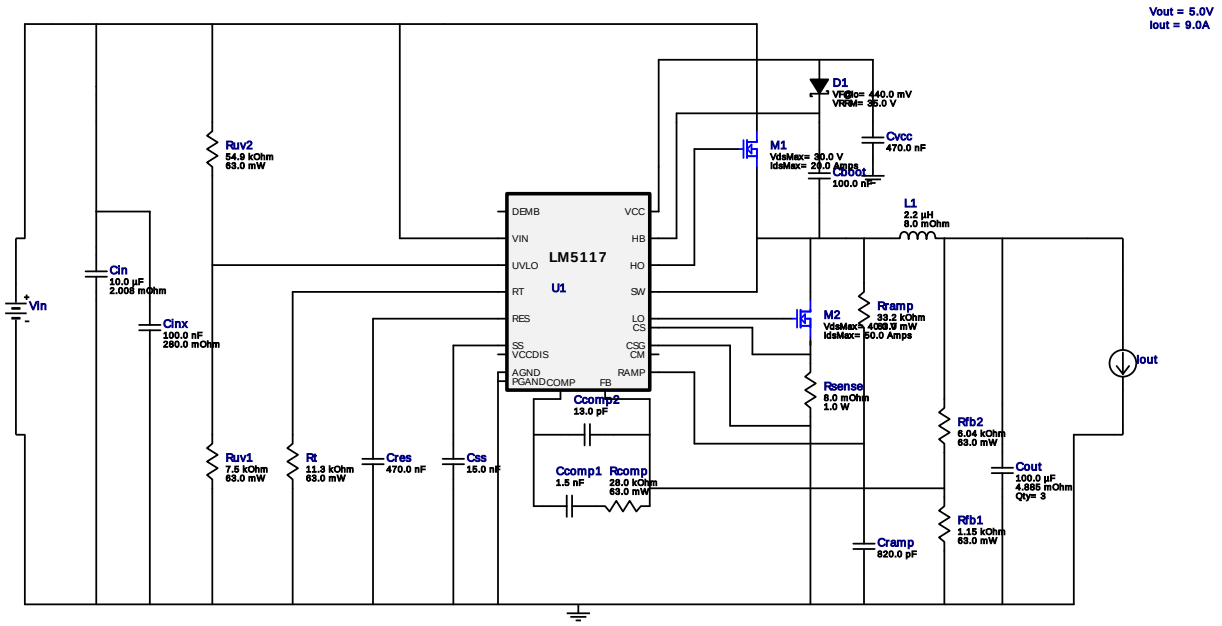
WEBENCH® Design Report

VinMin = 12.0V
VinMax = 20.0V
Vout = 5.0V
Iout = 9.0A

Device = LM5117PMHX/NOPB
Topology = Buck
Created = 8/12/16 1:07:09 AM
BOM Cost = $4.26
BOM Count = 25
Total Pd = 3.71W

Design : 1836019/64 LM5117PMHX/NOPB
LM5117PMHX/NOPB 12.0V-20.0V to 5.00V @ 9.0A



Electrical BOM

#	Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
1.	Cboot	MuRata	GRM155R61A104KA01D Series= X5R	Cap= 100.0 nF VDC= 10.0 V IRMS= 0.0 A	1	$0.01	0402 3 mm²
2.	Ccomp1	Yageo America	CC0805KRX7R9BB152 Series= X7R	Cap= 1.5 nF VDC= 50.0 V IRMS= 0.0 A	1	$0.01	0805 7 mm²
3.	Ccomp2	Samsung Electro-Mechanics	CL21C130JBANNNC Series= C0G/NP0	Cap= 13.0 pF VDC= 50.0 V IRMS= 0.0 A	1	$0.01	0805 7 mm²
4.	Cin	MuRata	GRM32ER7YA106KA12L Series= X7R	Cap= 10.0 uF ESR= 2.008 mOhm VDC= 35.0 V IRMS= 4.6772 A	1	$0.22	1210_280 15 mm²
5.	Cinx	AVX	08053C104KAT2A Series= X7R	Cap= 100.0 nF ESR= 280.0 mOhm VDC= 25.0 V IRMS= 0.0 A	1	$0.01	0805 7 mm²
6.	Cout	MuRata	GRM31CR60J107ME39L Series= X5R	Cap= 100.0 uF ESR= 4.885 mOhm VDC= 6.3 V IRMS= 4.4118 A	3	$0.14	1206_190 11 mm²
7.	Cramp	Yageo America	CC0805KRX7R9BB821 Series= X7R	Cap= 820.0 pF VDC= 50.0 V IRMS= 0.0 A	1	$0.01	0805 7 mm²
8.	Cres	MuRata	GRM155C80J474KE19D Series= X6S	Cap= 470.0 nF VDC= 6.3 V IRMS= 0.0 A	1	$0.01	0402 3 mm²

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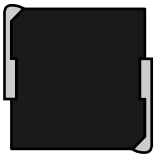
#	Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
9.	Css	Yageo America	CC0805KRX7R9BB153 Series= X7R	Cap= 15.0 nF VDC= 50.0 V IRMS= 0.0 A	1	$0.01	 0805 7 mm²
10.	Cvcc	MuRata	GRM155R61A474KE15D Series= X5R	Cap= 470.0 nF VDC= 10.0 V IRMS= 0.0 A	1	$0.01	 0402 3 mm²
11.	D1	Bourns	CD0603-B0130L	VF@Io= 440.0 mV VRRM= 35.0 V	1	$0.09	 Diode_0603 5 mm²
12.	L1	Bourns	SRP1235-2R2M	L= 2.2 µH DCR= 8.0 mOhm	1	$0.53	 SRP1235 253 mm²
13.	M1	Texas Instruments	CSD17579Q3A	VdsMax= 30.0 V IdsMax= 20.0 Amps	1	$0.19	 TRANS_NexFET_Q3A 18 mm²
14.	M2	Texas Instruments	CSD18504Q5A	VdsMax= 40.0 V IdsMax= 50.0 Amps	1	$0.37	 TRANS_NexFET_Q5A 55 mm²
15.	Rcomp	Vishay-Dale	CRCW040228K0FKED Series= CRCW..e3	Res= 28.0 kOhm Power= 63.0 mW Tolerance= 1.0%	1	$0.01	 0402 3 mm²
16.	Rfb1	Vishay-Dale	CRCW04021K15FKED Series= CRCW..e3	Res= 1.15 kOhm Power= 63.0 mW Tolerance= 1.0%	1	$0.01	 0402 3 mm²
17.	Rfb2	Vishay-Dale	CRCW04026K04FKED Series= CRCW..e3	Res= 6.04 kOhm Power= 63.0 mW Tolerance= 1.0%	1	$0.01	 0402 3 mm²
18.	Rramp	Vishay-Dale	CRCW040233K2FKED Series= CRCW..e3	Res= 33.2 kOhm Power= 63.0 mW Tolerance= 1.0%	1	$0.01	 0402 3 mm²
19.	Rsense	Susumu Co Ltd	PRL1632-R008-F-T1 Series= PRL1632	Res= 8.0 mOhm Power= 1.0 W Tolerance= 1.0%	1	$0.19	 0612 11 mm²
20.	Rt	Vishay-Dale	CRCW040211K3FKED Series= CRCW..e3	Res= 11.3 kOhm Power= 63.0 mW Tolerance= 1.0%	1	$0.01	 0402 3 mm²
21.	Ruv1	Vishay-Dale	CRCW04027K50FKED Series= CRCW..e3	Res= 7.5 kOhm Power= 63.0 mW Tolerance= 1.0%	1	$0.01	 0402 3 mm²
22.	Ruv2	Vishay-Dale	CRCW040254K9FKED Series= CRCW..e3	Res= 54.9 kOhm Power= 63.0 mW Tolerance= 1.0%	1	$0.01	 0402 3 mm²
23.	U1	Texas Instruments	LM5117PMHX/NOPB	Switcher	1	$2.10	 PWP0020A 71 mm²

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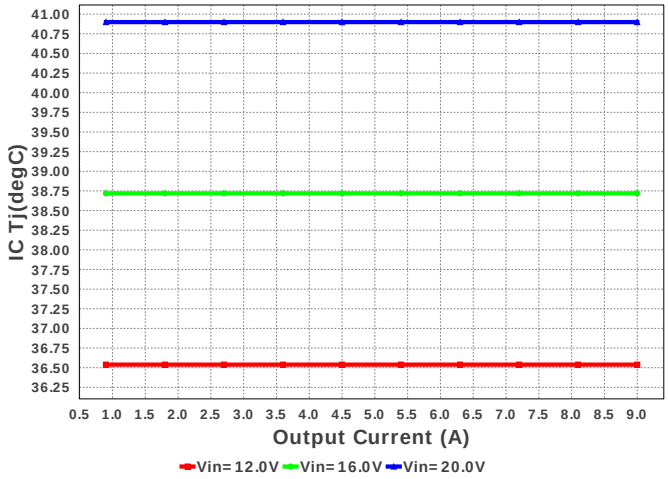
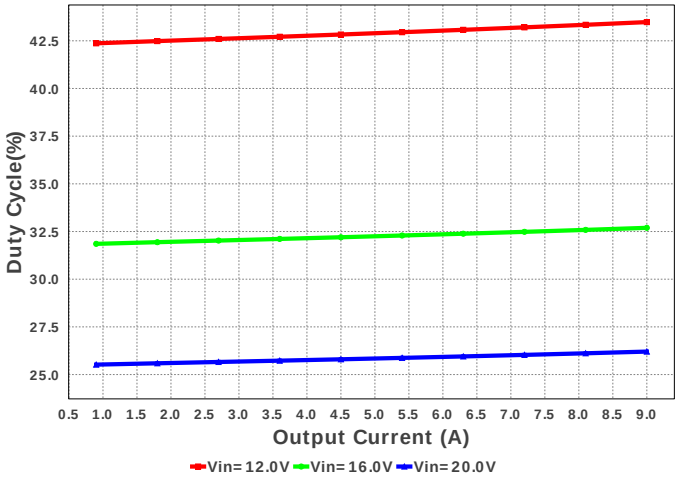
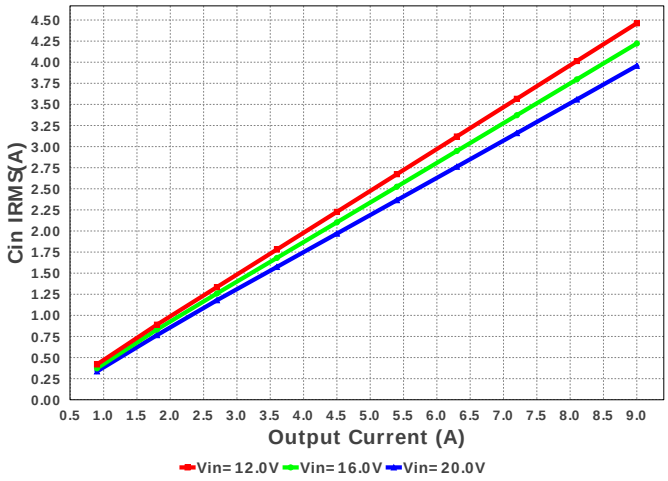


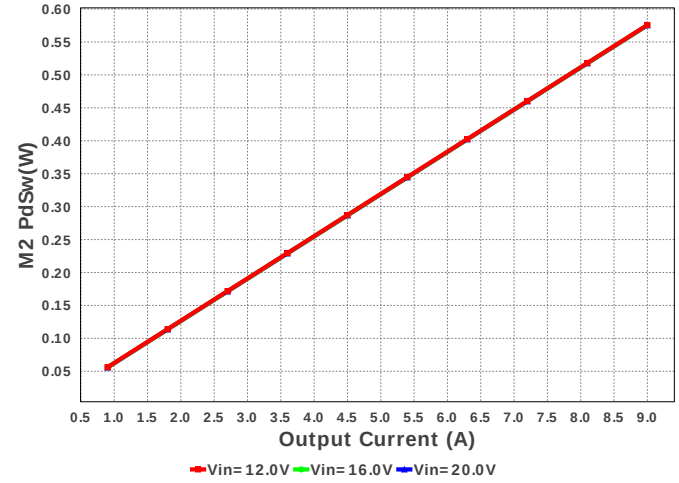
Duty Cycle



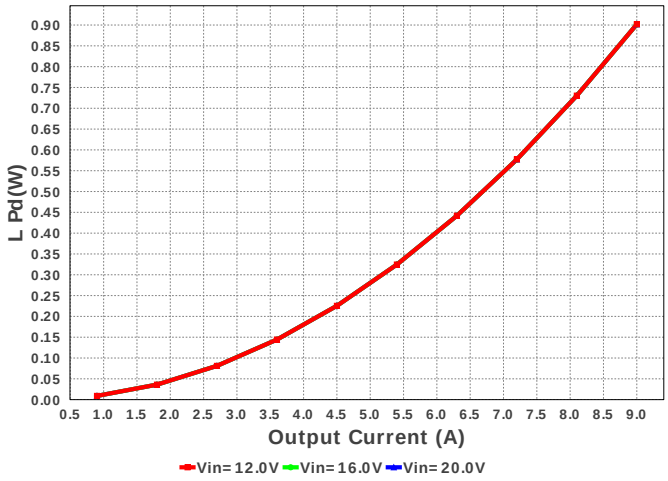
Cin IRMS



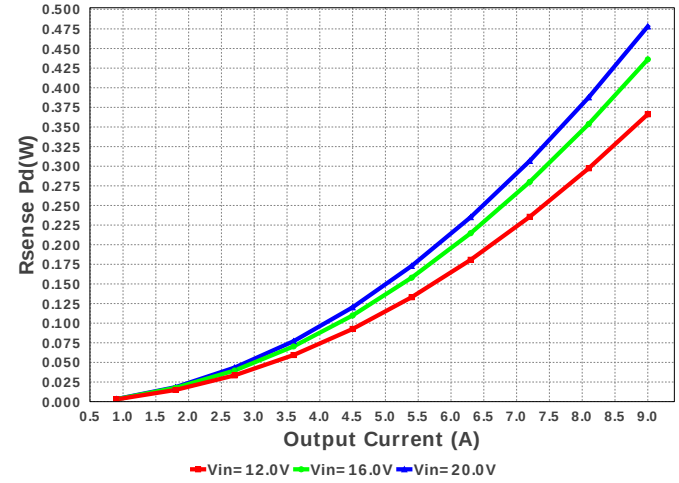
M2 PdSw



L Pd



Rsense Pd



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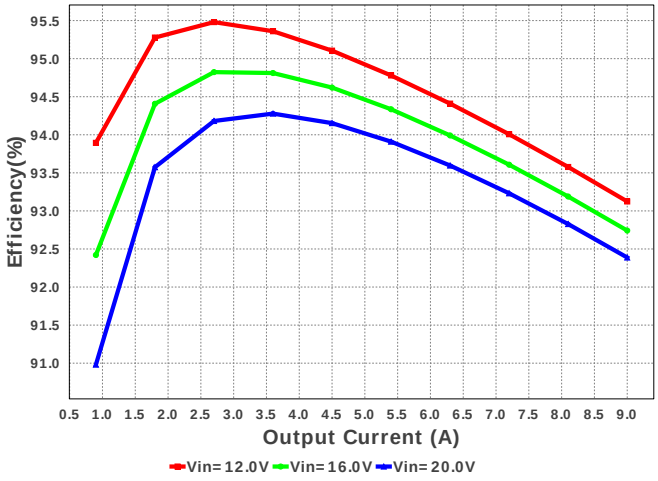
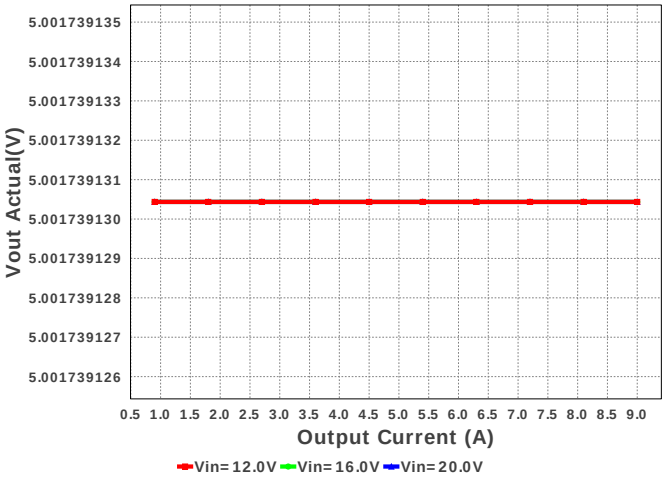
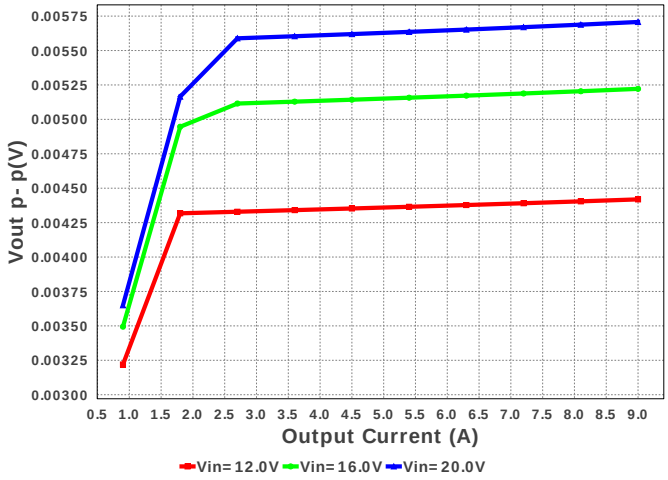
Efficiency



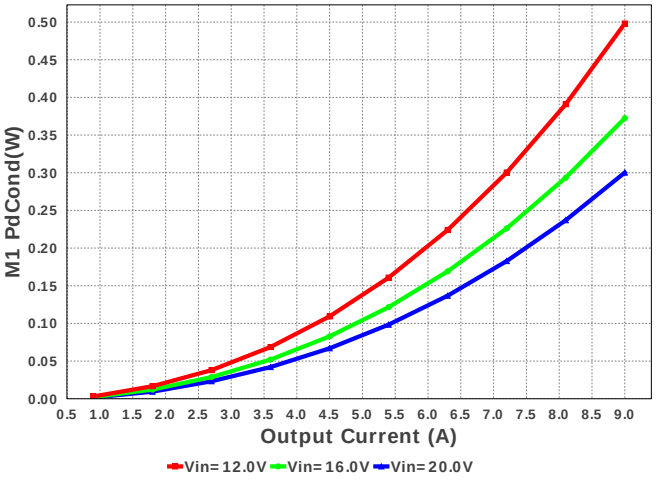
Vout Actual



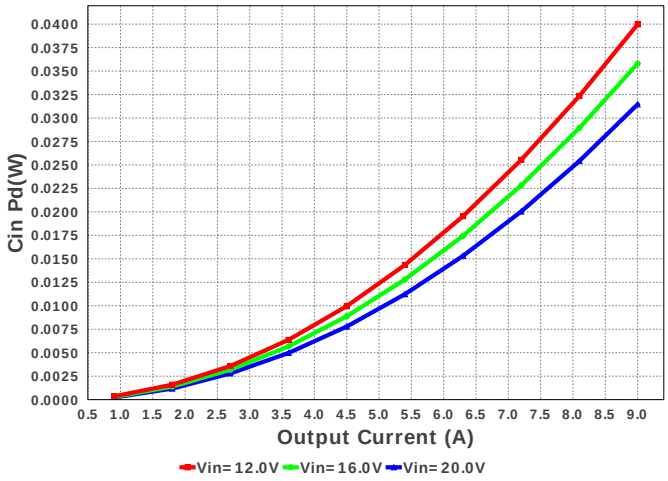
Vout p- p



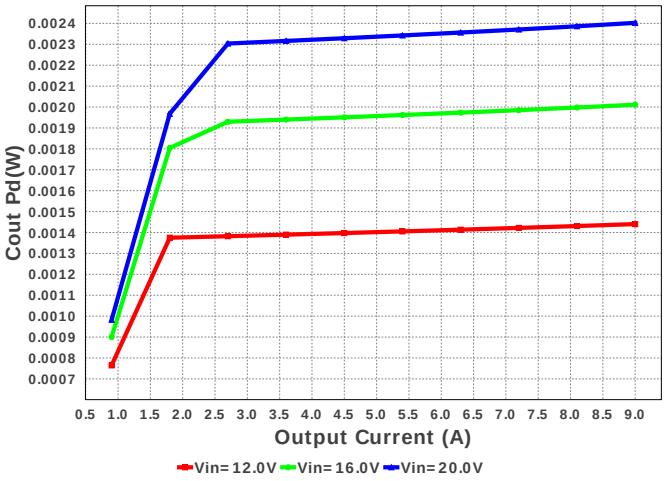
M1 PdCond



Cin Pd



Cout Pd



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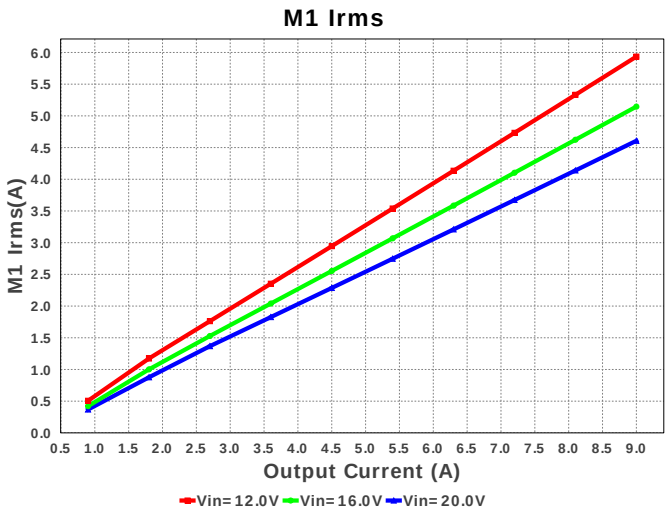

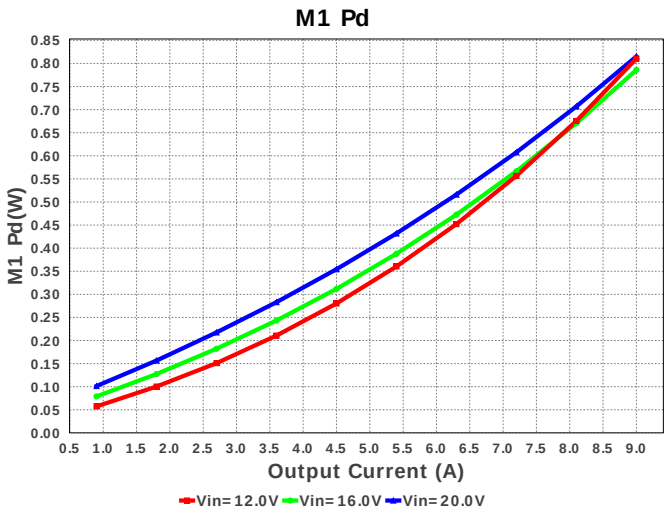

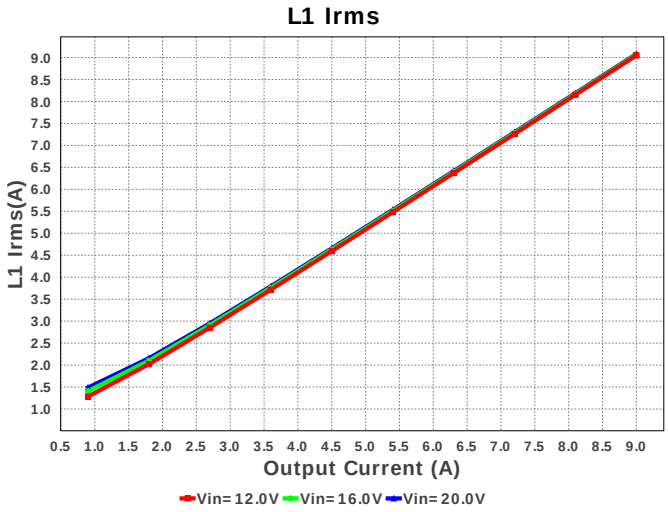

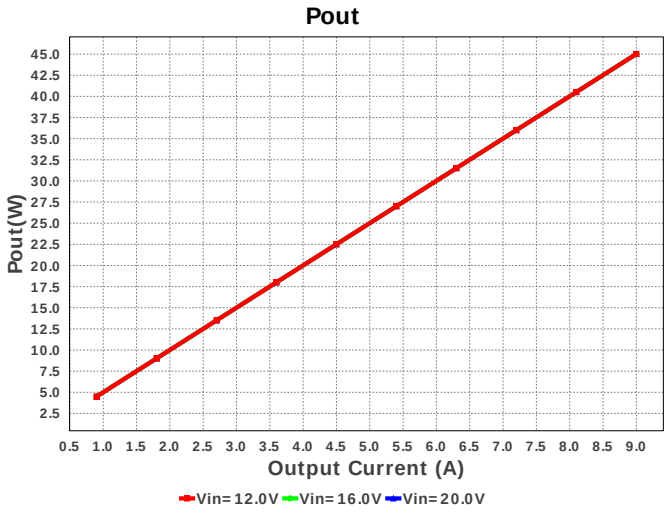

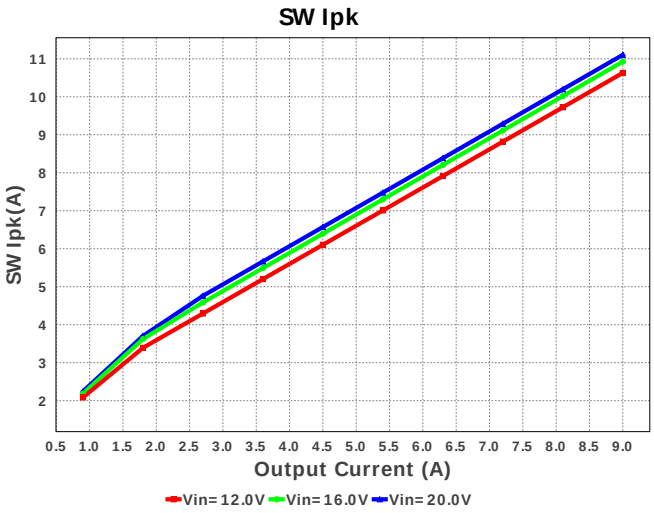

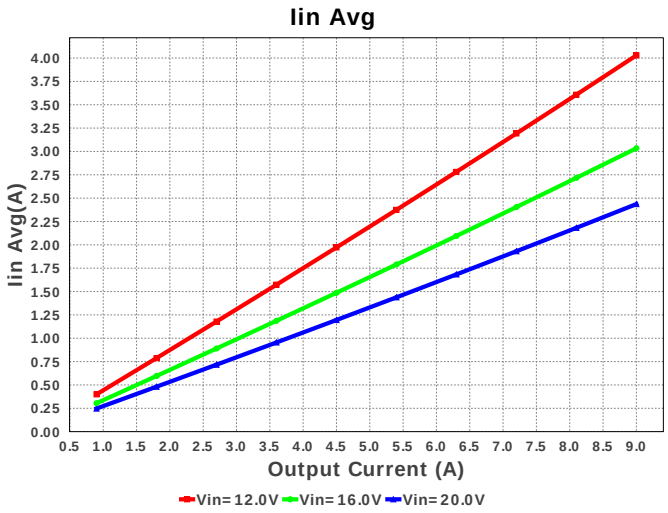

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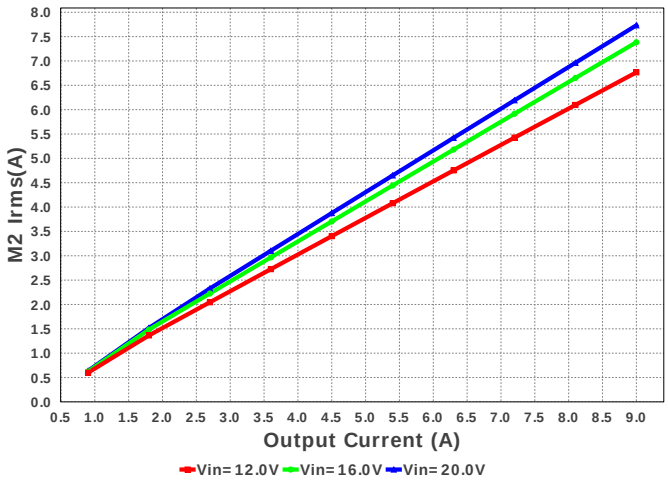

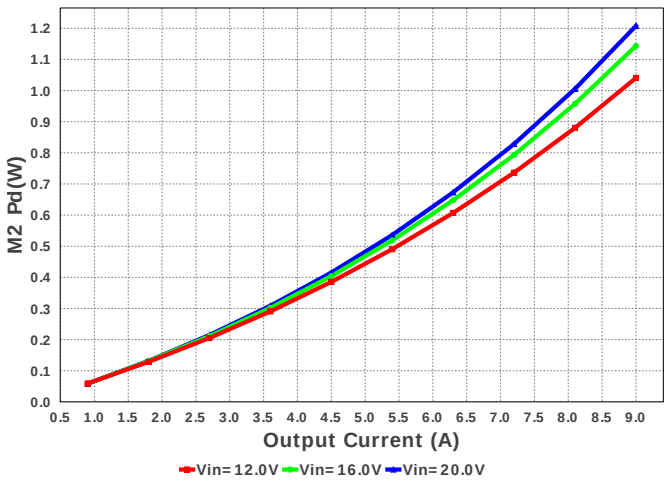

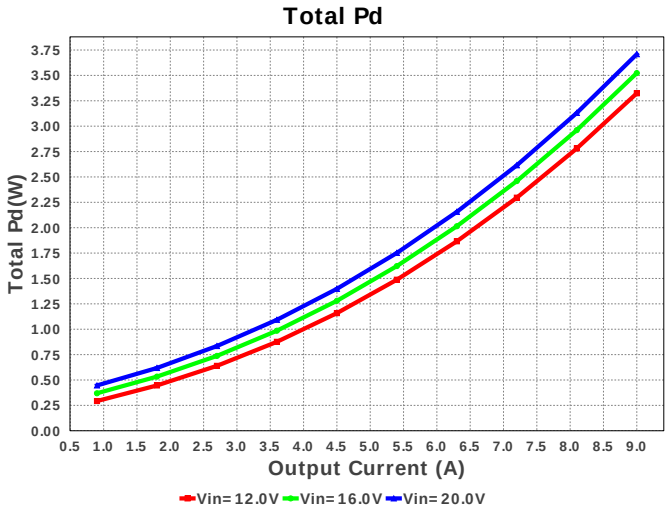

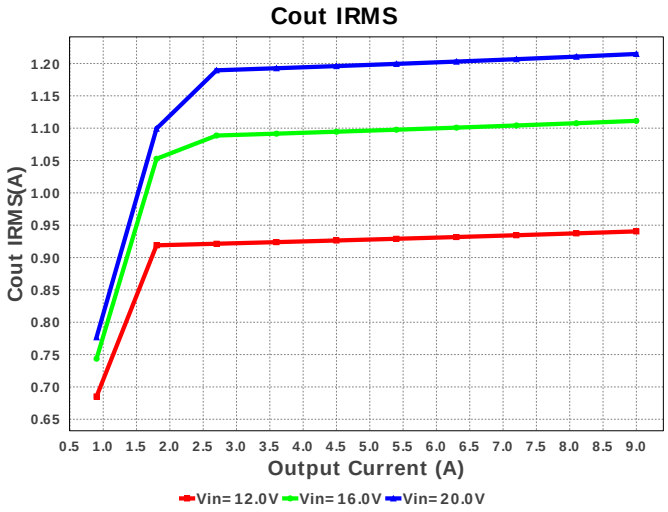

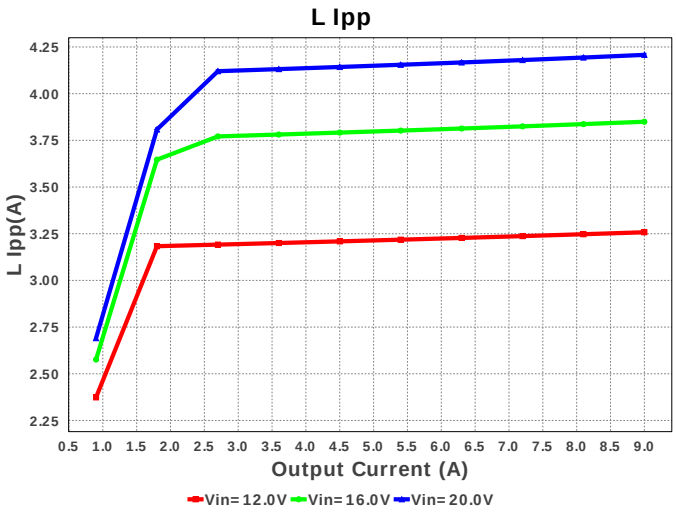

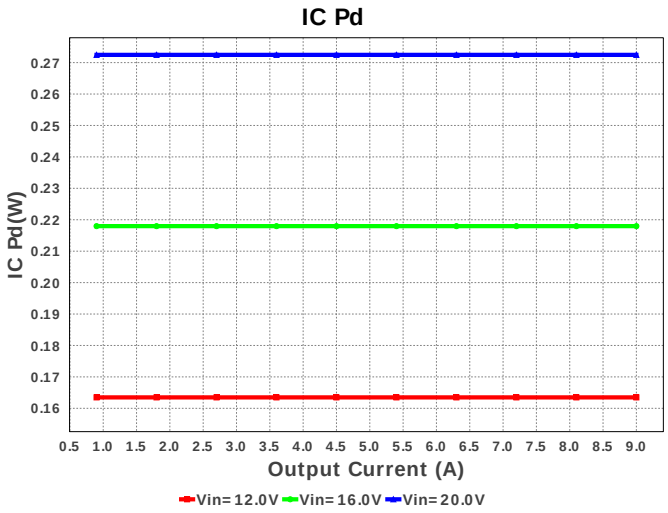

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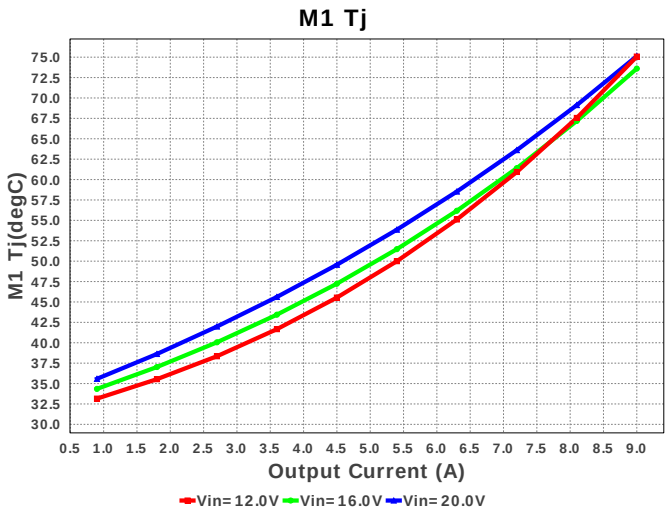

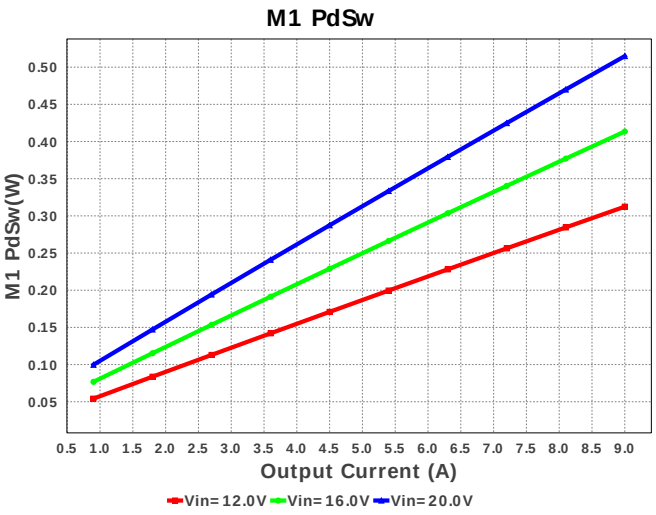

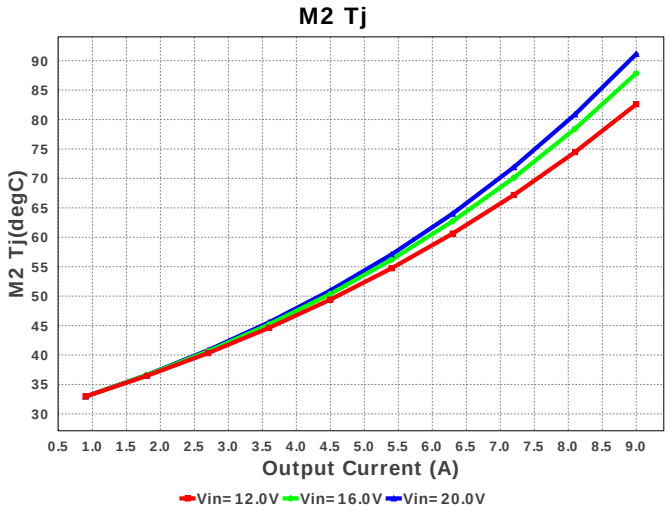

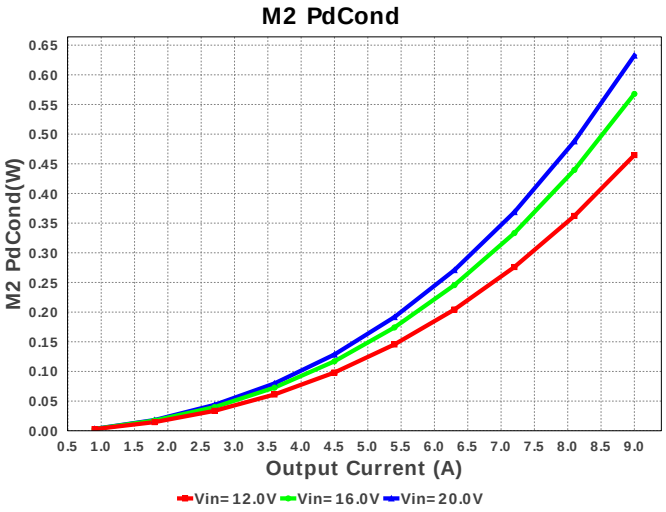

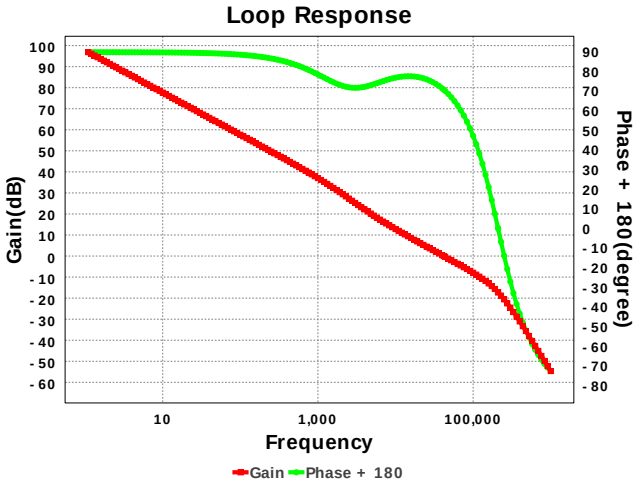

Operating Values

#	Name	Value	Category	Description
1.	Cin IRMS	3.958 A	Current	Input capacitor RMS ripple current
2.	Cout IRMS	1.215 A	Current	Output capacitor RMS ripple current
3.	Iin Avg	2.436 A	Current	Average input current
4.	L Ipp	4.208 A	Current	Peak-to-peak inductor ripple current
5.	L1 Irms	9.081 A	Current	Inductor ripple current
6.	M1 Irms	4.607 A	Current	MOSFET RMS ripple current
7.	M2 Irms	7.731 A	Current	MOSFET RMS ripple current
8.	SW Ipk	11.104 A	Current	Peak switch current
9.	BOM Count	25	General	Total Design BOM count
10.	FootPrint	525.0 mm^2	General	Total Foot Print Area of BOM components
11.	Frequency	424.559 kHz	General	Switching frequency

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#	Name	Value	Category	Description
12.	IC Tolerance	12.0 mV	General	IC Feedback Tolerance
13.	Mode	CCM	General	Conduction Mode
14.	Pout	45.016 W	General	Total output power
15.	Total BOM	$4.26	General	Total BOM Cost
16.	Low Freq Gain	96.859 dB	Op_Point	Gain at 10Hz
17.	Vout Actual	5.002 V	Op_Point	Vout Actual calculated based on selected voltage divider resistors
18.	Vout OP	5.002 V	Op_Point	Operational Output Voltage
19.	Cross Freq	41.824 kHz	Op_point	Bode plot crossover frequency
20.	Duty Cycle	26.204 %	Op_point	Duty cycle
21.	Efficiency	92.383 %	Op_point	Steady state efficiency
22.	Gain Marg	-17.265 dB	Op_point	Bode Plot Gain Margin
23.	IC Tj	40.987 degC	Op_point	IC junction temperature
24.	IOUT_OP	9.0 A	Op_point	Iout operating point
25.	M1 Tj	75.132 degC	Op_point	M1 MOSFET junction temperature
26.	M2 Tj	91.143 degC	Op_point	M2 MOSFET junction temperature
27.	Phase Marg	70.906 deg	Op_point	Bode Plot Phase Margin
28.	VIN_OP	20.0 V	Op_point	Vin operating point
29.	Vout p-p	5.709 mV	Op_point	Peak-to-peak output ripple voltage
30.	Cin Pd	31.452 mW	Power	Input capacitor power dissipation
31.	Cout Pd	2.402 mW	Power	Output capacitor power dissipation
32.	IC Pd	274.675 mW	Power	IC power dissipation
33.	L Pd	901.705 mW	Power	Inductor power dissipation
34.	M1 Pd	815.066 mW	Power	M1 MOSFET total power dissipation
35.	M1 PdCond	300.194 mW	Power	M1 MOSFET conduction losses
36.	M1 PdSw	514.872 mW	Power	M1 MOSFET switching losses
37.	M2 Pd	1.208 W	Power	M2 MOSFET total power dissipation
38.	M2 PdCond	632.512 mW	Power	M2 MOSFET conduction losses
39.	M2 PdSw	575.282 mW	Power	M2 MOSFET switching losses
40.	Rsense Pd	478.198 mW	Power	LED Current Rsns Power Dissipation
41.	Total Pd	3.711 W	Power	Total Power Dissipation
42.	Vout Tolerance	3.222 %		Vout Tolerance based on IC Tolerance (no load) and voltage divider resistors if applicable

Design Inputs

#	Name	Value	Description
1.	Iout	9.0	Maximum Output Current
2.	VinMax	20.0	Maximum input voltage
3.	VinMin	12.0	Minimum input voltage
4.	Vout	5.0	Output Voltage
5.	base_pn	LM5117	Base Product Number
6.	source	DC	Input Source Type
7.	Ta	30.0	Ambient temperature

Design Assistance

1. Outline The LM5117 is a synchronous buck controller intended for step-down regulator applications from a high voltage or widely varying input supply. The control method is based upon current mode control utilizing an emulated current ramp. Current mode control provides inherent line feed-forward, cycle-by-cycle current limiting and ease of loop compensation. The use of an emulated control ramp reduces noise sensitivity of the pulse-width modulation circuit, allowing reliable control of very small duty cycles necessary in high input voltage applications. External Vcc An output voltage derived bias supply can be applied to the VCC pin to reduce the controller power dissipation at higher input voltage. This can also relax constraints on the driver supply current if your external source can supply more than the LM5117 internal regulator. Please see Datasheet for more information. Diode Emulation A fully synchronous buck regulator implemented with a freewheel MOSFET rather than a diode has the capability to sink current from the output in certain conditions such as light load, over-voltage or pre-bias startup. The LM5117 provides a diode emulation feature that can be enabled to prevent reverse (drain to source) current flow in the low side free-wheel MOSFET.

2. **LM5117** Product Folder : http://www.ti.com/product/LM5117 : contains the data sheet and other resources.

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You should completely validate and test your design implementation to confirm the system functionality for your application prior to production.

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